



2SC5415AF-TD-E Information



For Reference Only

Part Number 2SC5415AF-TD-E Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - RF

Description TRANS NPN BIPO 0.1A 12V

Package TO-243AA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2SC5415AF-TD-E Specifications

Manufacturer Part Number	2SC5415AF-TD-E
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-243AA
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	12V
Frequency - Transition	6.7GHz
Noise Figure (dB Typ @ f)	1.1dB @ 1GHz
Gain	9dB
Power - Max	800mW
DC Current Gain (hFE) (Min) @ Ic, Vce	90 @ 30mA, 5V
Current - Collector (Ic) (Max)	100mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-243AA
Supplier Device Package	PCP
	Report errors?

2SC5415AF-TD-E Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2SC5415AF-TD-E Payment Methods



















2SC5415AF-TD-E Shipping Methods













If you have any question about 2SC5415AF-TD-E, please do not hesitate to contact us!

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